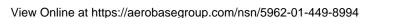
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Memory Microcircuit - Page 1 of 1





Operating Tempurature Range:

-5.50/+125.00 degrees celsius

Features Provided:

Low power and high speed

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

250.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

64k (8kx8) dual-port static ram, 68 pin quad flat pkg

Voltage Rating And Type Per Characteristic:

5.0 volts input

Time Rating Per Chacteristic:

35.00 nanoseconds access

Memory Device Type:

Ram

Terminal Type And Quantity:

68 leadless

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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